General Purpose Transistor

PNP Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-40	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-200	mAdc
Collector Current – Peak (Note 3)	I _{CM}	-800	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @ T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) @ T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

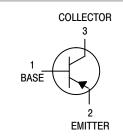
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.

3. Reference SOA curve.



ON Semiconductor®

www.onsemi.com





SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



2A = Specific Device Code

M = Date Code*

= Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may

vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]			
MMBT3906LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel			
MMBT3906LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel			
SMMBT3906LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel			
SMMBT3906LT3G	SOT–23 (Pb–Free)	10,000 / Tape & Reel			

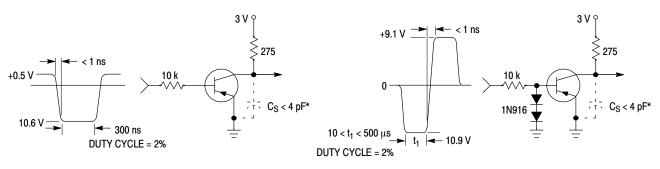
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Charac	teristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$		V _{(BR)CEO}	-40	-	Vdc
Collector–Base Breakdown Voltage $(I_C = -10 \ \mu Adc, I_E = 0)$		V _{(BR)CBO}	-40	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	-5.0	-	Vdc
Base Cutoff Current (V _{CE} = -30 Vdc, V _{EB} = -3.0 Vdc)		I _{BL}	_	-50	nAdc
Collector Cutoff Current (V _{CE} = -30 Vdc, V _{EB} = -3.0 Vdc)		ICEX	_	-50	nAdc
ON CHARACTERISTICS (Note 4)					
$ \begin{array}{l} \text{DC Current Gain} \\ (I_C = -0.1 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc} \\ (I_C = -1.0 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc} \\ (I_C = -10 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -50 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -100 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \end{array} $)	H _{FE}	60 80 100 60 30	_ 300 _	_
Collector – Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}, I_B = -1.0 \text{ mAdc}$) ($I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$)		V _{CE(sat)}		-0.25 -0.4	Vdc
$\begin{array}{l} \text{Base-Emitter Saturation Voltage} \\ (I_C = -10 \text{ mAdc}, \text{ I}_B = -1.0 \text{ mAdc}) \\ (I_C = -50 \text{ mAdc}, \text{ I}_B = -5.0 \text{ mAdc}) \end{array}$		V _{BE(sat)}	-0.65 -	-0.85 -0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS					
$\label{eq:current-Gain-Bandwidth Product} \begin{split} Current-Gain-Bandwidth Product \\ (I_C = -10 \text{ mAdc}, \text{ V}_{CE} = -20 \text{ Vdc}, \end{split}$	f = 100 MHz)	f _T	250	-	MHz
Output Capacitance $(V_{CB} = -5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ M})$	Hz)	C _{obo}	_	4.5	pF
Input Capacitance (V _{EB} = -0.5 Vdc, I _C = 0, f = 1.0 M	Hz)	C _{ibo}	_	10	pF
Input Impedance $(I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz})$		h _{ie}	2.0	12	kΩ
Voltage Feedback Ratio (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)		h _{re}	0.1	10	X 10 ⁻⁴
Small-Signal Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, f = 1.0 kHz)		h _{fe}	100	400	_
Output Admittance ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, f = 1.0 kHz)		h _{oe}	3.0	60	μmhos
Noise Figure (I _C = -100 μ Adc, V _{CE} = -5.0 Vdc, R _S = 1.0 kΩ, f = 1.0 kHz)		NF	_	4.0	dB
SWITCHING CHARACTERISTICS					
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc},$	t _d	-	35	

Delay Time		$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc}, \\ I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t _d	-	35	00	
Rise Time			tr	-	35	ns	
Storage Tim	e	$(V_{CC} = -3.0 \text{ Vdc}, I_C = -10 \text{ mAdc}, I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	t _s	-	225	ns	Ī
Fall Time			t _f	-	75	115	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

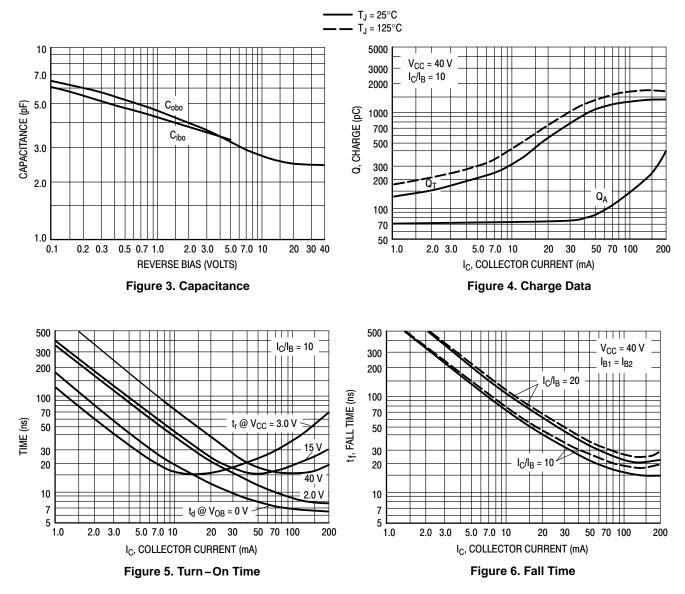


* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS



TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, \text{ Bandwidth} = 1.0 \text{ Hz})$

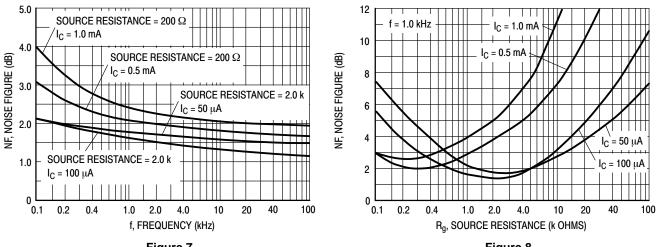
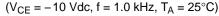
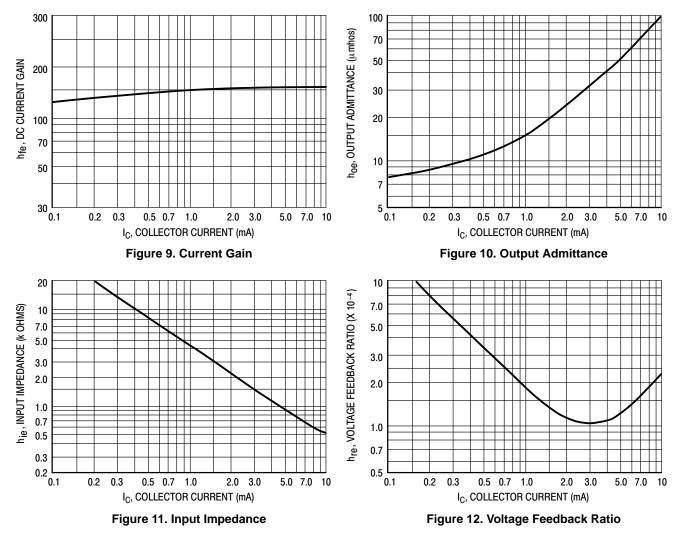


Figure 7.

Figure 8.





TYPICAL STATIC CHARACTERISTICS

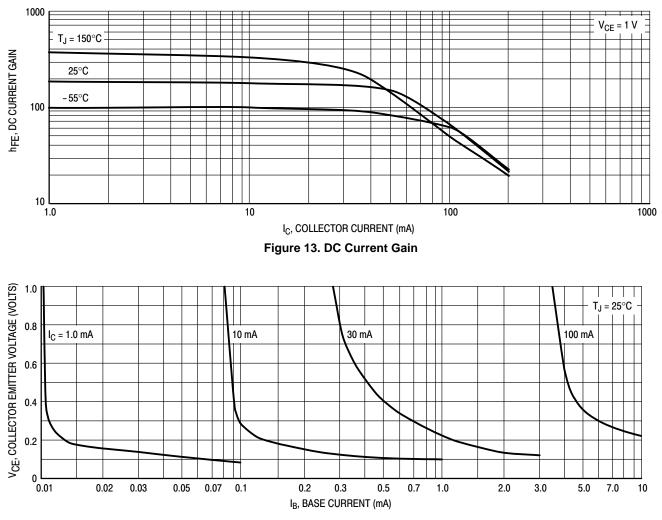
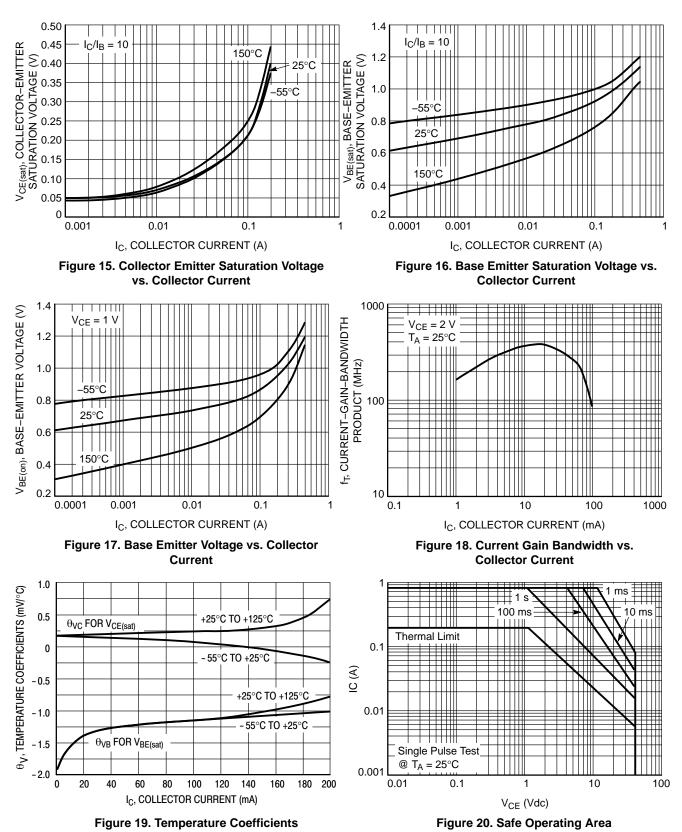


Figure 14. Collector Saturation Region







© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

MMBT3906LT1 MMBT3906LT1G MMBT3906LT3 MMBT3906LT3G SMMBT3906LT3G SMMBT3906LT1G